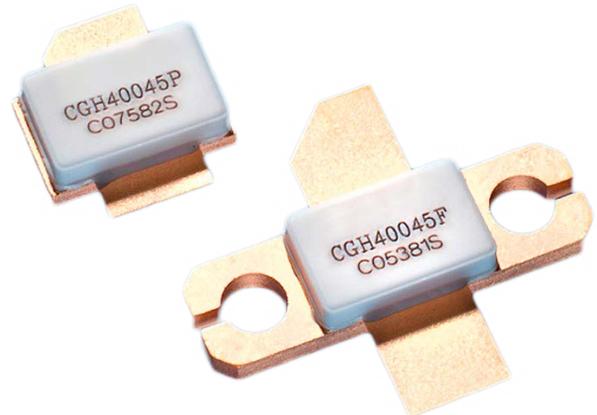


CGH40045

45 W, DC - 4 GHz RF Power GaN HEMT

Description

The CGH40045 is an unmatched, gallium nitride (GaN) high-electron mobility transistor (HEMT). The CGH40045, operating from a 28 volt rail, offers a general purpose, broadband solution to a variety of RF and microwave applications. GaN HEMT offer high efficiency, high gain and wide bandwidth capabilities making the CGH40045 ideal for linear and compressed amplifier circuits. The transistor is available in a flange and pill package.



Package Types: 440193 & 440206
PN's: CGH40045F & CGH40045P

Features

- Up to 4 GHz Operation
- 16 dB Small Signal Gain at 2.0 GHz
- 12 dB Small Signal Gain at 4.0 GHz
- 55 W Typical P_{SAT}
- 55% Efficiency at P_{SAT}
- 28 V Operation

Applications

- 2-Way Private Radio
- Broadband Amplifiers
- Cellular Infrastructure
- Test Instrumentation
- Class A, AB, Linear amplifiers suitable for OFDM, W-CDMA, EDGE, CDMA waveforms



Large Signal Models Available for ADS and MWO



Absolute Maximum Ratings (not simultaneous) at 25°C Case Temperature

Parameter	Symbol	Rating	Units	Conditions
Drain-Source Voltage	V_{DSS}	120	V	25°C
Gate-to-Source Voltage	V_{GS}	-10, +2		
Storage Temperature	T_{STG}	-65, +150	°C	
Operating Junction Temperature	T_J	225		
Maximum Forward Gate Current	I_{GMAX}	15	mA	25°C
Maximum Drain Current ¹	I_{DMAX}	6		
Soldering Temperature ²	T_S	245	°C	
Screw Torque	τ	40	in-oz	
Thermal Resistance, Junction to Case ³	$R_{\theta JC}$	2.8	°C/W	85°C
Case Operating Temperature ^{3,4}	T_C	-40, +150	°C	

Notes:

¹ Current limit for long term, reliable operation

² Refer to the Application Note on soldering

³ Measured for the CGH40045F at $P_{DISS} = 56$ W

⁴ See also, the Power Dissipation De-rating Curve on Page 8

Electrical Characteristics ($T_C = 25^\circ\text{C}$)

Characteristics	Symbol	Min.	Typ.	Max.	Units	Conditions
DC Characteristics¹						
Gate Threshold Voltage	$V_{GS(th)}$	-3.8	-3.0	-2.3	V_{DC}	$V_{DS} = 10$ V, $I_D = 14.4$ mA
Gate Quiescent Voltage	$V_{GS(Q)}$	-	-2.7	-		$V_{DS} = 28$ V, $I_D = 400$ mA
Saturated Drain Current ²	I_{DS}	11.6	14.0	-	A	$V_{DS} = 6.0$ V, $V_{GS} = 2.0$ V
Drain-Source Breakdown Voltage	V_{BR}	84	-	-	V_{DC}	$V_{GS} = -8$ V, $I_D = 14.4$ mA
RF Characteristics³ ($T_C = 25^\circ\text{C}$, $F_0 = 2.5$ GHz unless otherwise noted)						
Small Signal Gain	G_{SS}	12.5	14	-	dB	$V_{DD} = 28$ V, $I_{DQ} = 400$ mA
Power Output ⁴	P_{SAT}	40	55	-	W	
Drain Efficiency ⁵	η	45		-	-	%
Output Mismatch Stress	VSWR	-	-	10 : 1	Ψ	No damage at all phase angles, $V_{DD} = 28$ V, $I_{DQ} = 400$ mA, $P_{OUT} = 45$ W CW
Dynamic Characteristics						
Input Capacitance	C_{GS}	-	19.0	-	pF	$V_{DS} = 28$ V, $V_{GS} = -8$ V, $f = 1$ MHz
Output Capacitance	C_{DS}	-	5.9	-		
Feedback Capacitance	C_{GD}	-	0.8	-		

Notes:

¹ Measured on wafer prior to packaging

² Scaled from PCM data

³ Measured in CGH40045F-AMP

⁴ P_{SAT} is defined as $I_G = 1.08$ mA

⁵ Drain Efficiency = P_{OUT} / P_{DC}

2

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Rev. 5.0, 2022-8-4

Typical Performance

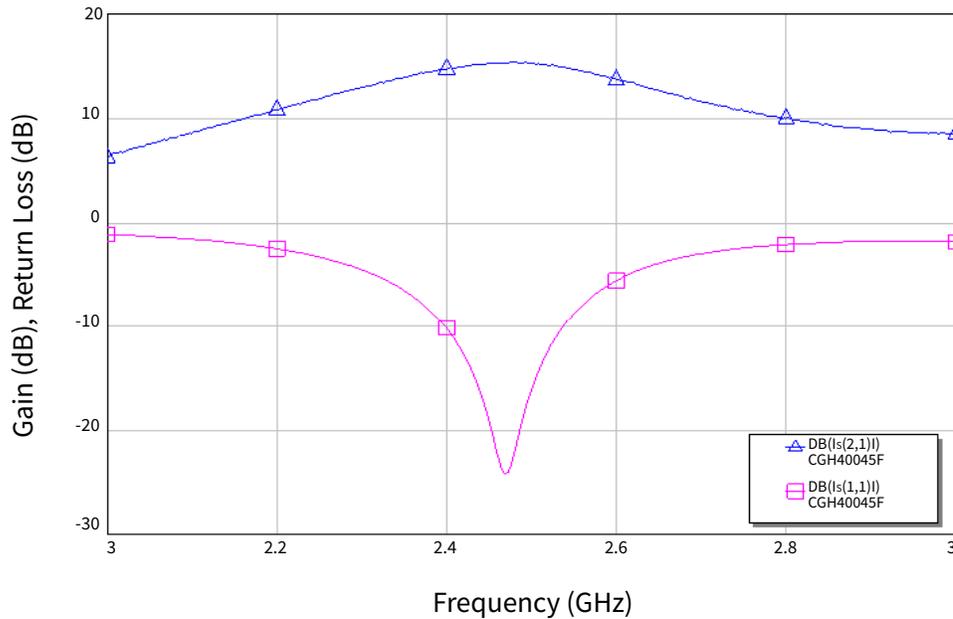


Figure 1. Simulated Small Signal Gain and Input Return Loss of the CGH40045F-AMP vs Frequency

$$V_{DD} = 28 \text{ V}, I_{DQ} = 400 \text{ mA}$$

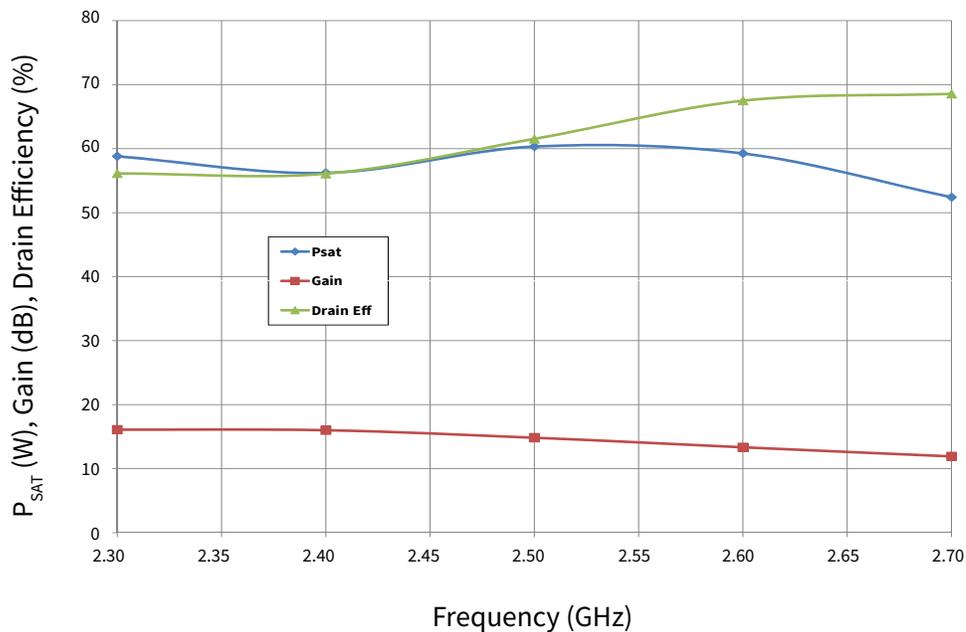


Figure 2. Gain, Efficiency, and Output Power vs Frequency measured in Amplifier Circuit CGH40045F-AMP

$$V_{DD} = 28 \text{ V}, I_{DQ} = 400 \text{ mA}$$

Typical Performance

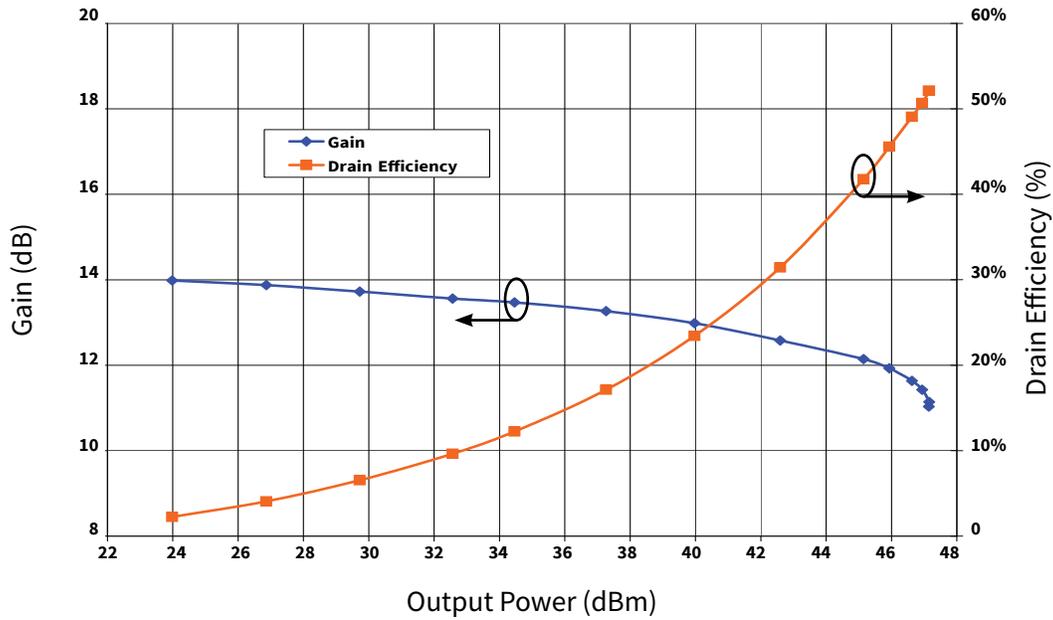


Figure 3. Gain and Efficiency vs Output Power measured in Amplifier Circuit CGH40045F-AMP
 $V_{DD} = 28\text{ V}$, $I_{DQ} = 400\text{ mA}$, Freq = 2.5 GHz

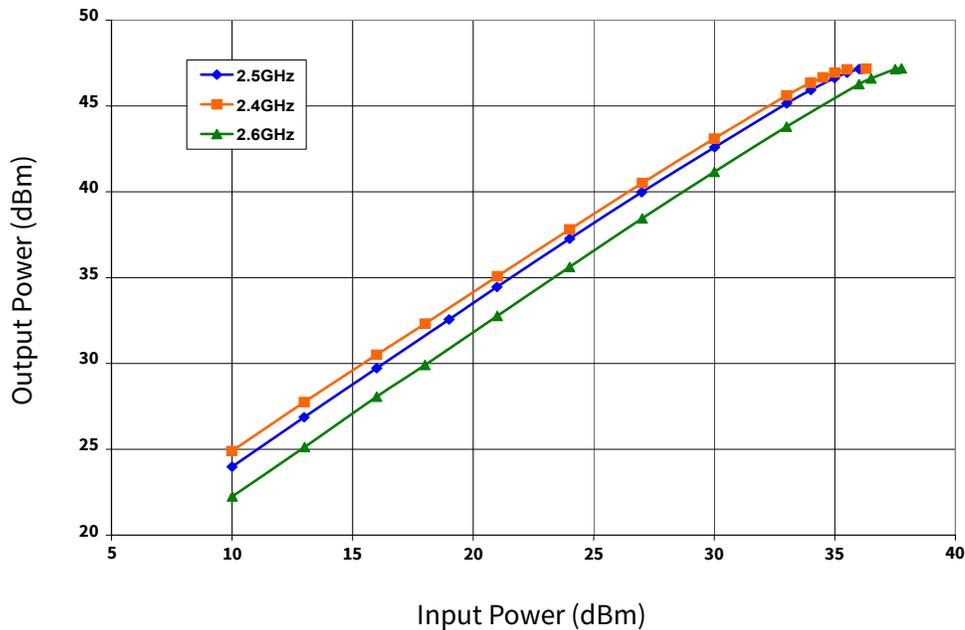


Figure 4. Single Tone CW Output Power vs Input Power measured in Amplifier Circuit CGH40045F-AMP
 $V_{DD} = 28\text{ V}$, $I_{DQ} = 400\text{ mA}$

Typical Performance

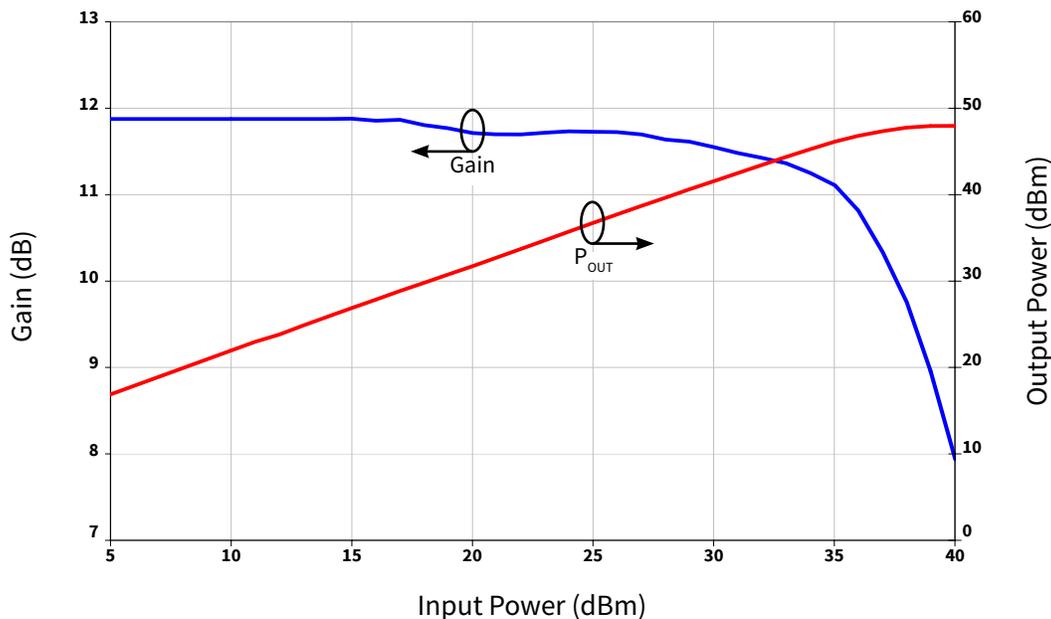


Figure 5. Pulsed Gain and Output Power vs Input Power measured in Amplifier Circuit CGH40045F-AMP
 $V_{DD} = 28\text{ V}$, $I_{DQ} = 800\text{ mA}$, Freq = 3.6 GHz, Pulse Width = 200 μs , 10% Duty Cycle

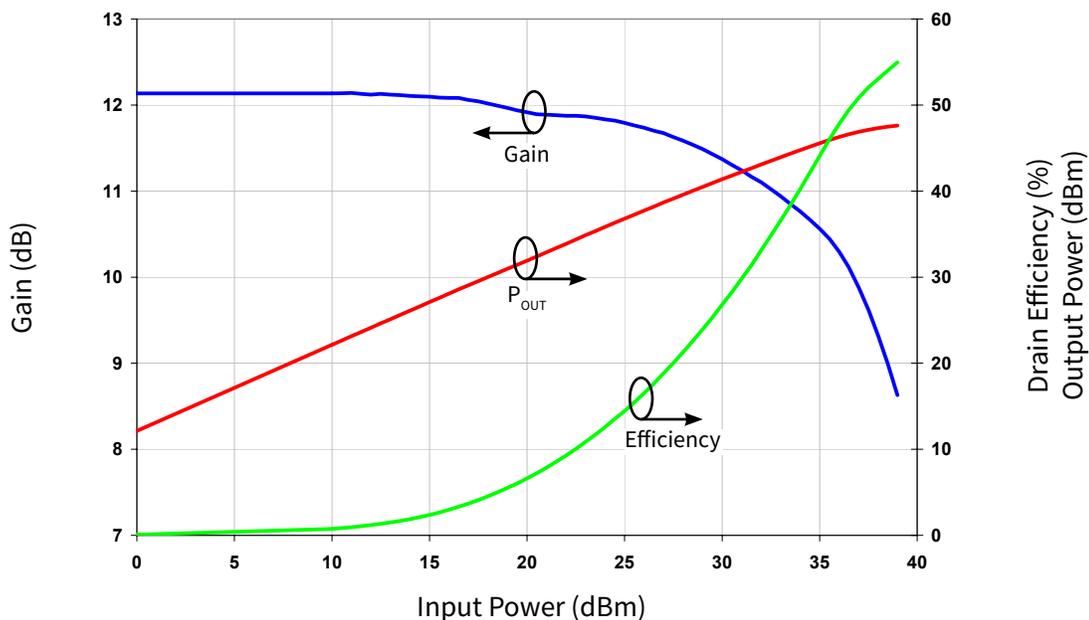


Figure 6. Single Tone CW Gain, Efficiency, and Output Power vs Input Power measured in Amplifier Circuit CGH40045F-AMP
 $V_{DD} = 28\text{ V}$, $I_{DQ} = 800\text{ mA}$, Freq = 3.6 GHz

Typical Performance

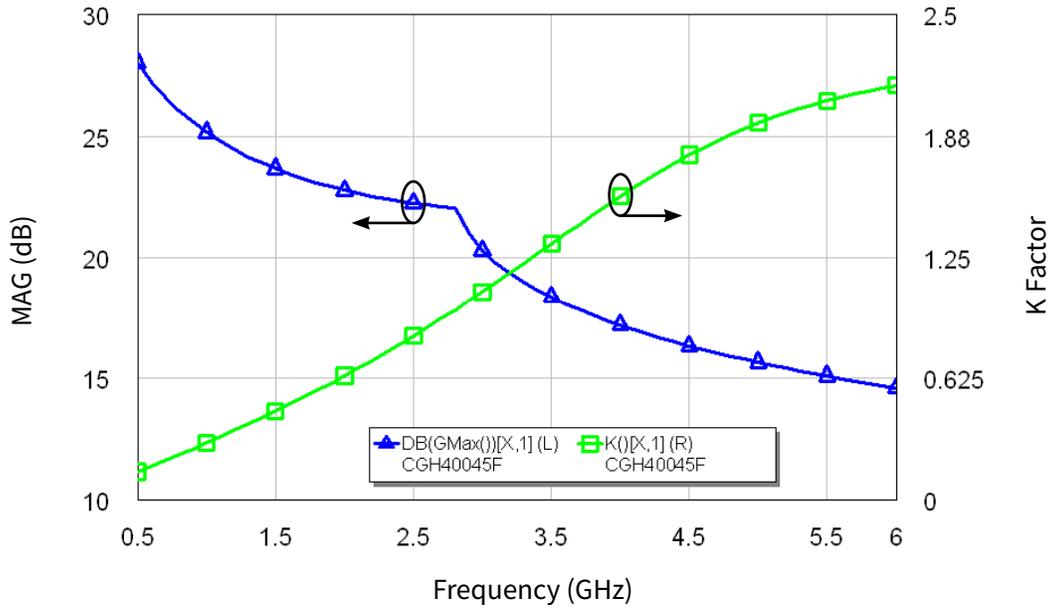


Figure 7. Simulated Maximum Available Gain and K Factor of the CGH40045
 $V_{DD} = 28\text{ V}$, $I_{DQ} = 400\text{ mA}$

Typical Performance

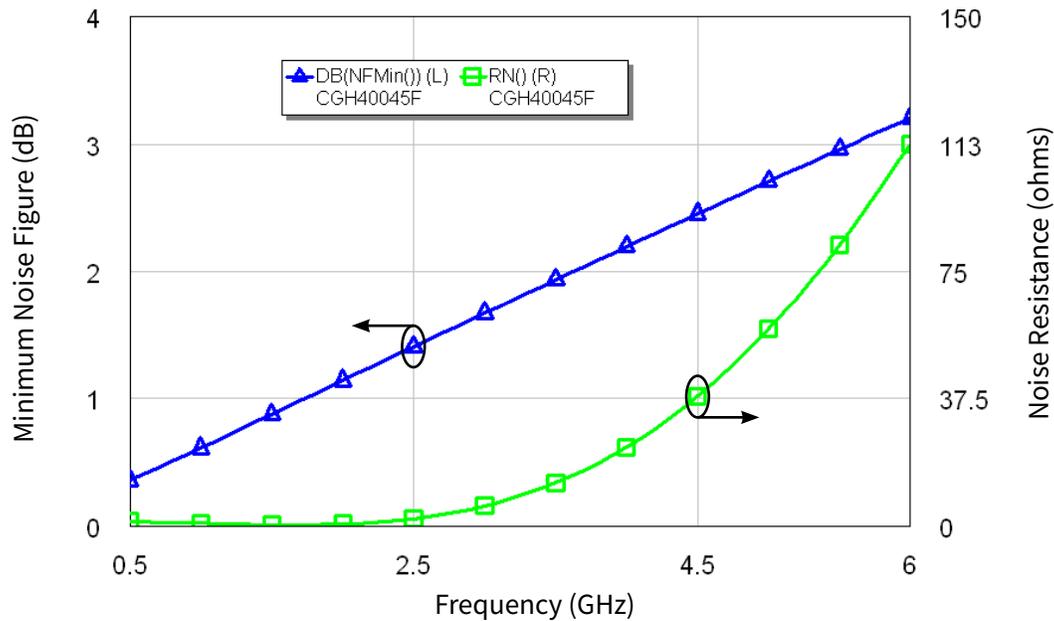
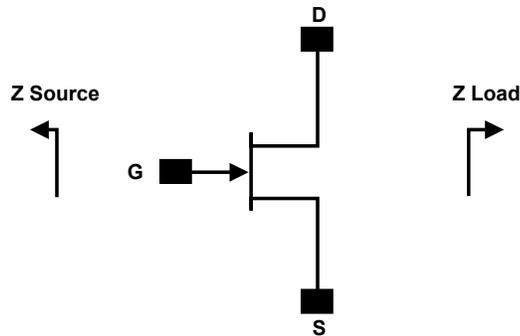


Figure 8. Simulated Minimum Noise Figure and Noise Resistance vs Frequency of the CGH40045
 $V_{DD} = 28\text{ V}$, $I_{DQ} = 400\text{ mA}$

Electrostatic Discharge (ESD) Classifications

Parameter	Symbol	Class	Classification Levels	Test Methodology
Human Body Model	HBM	1A	ANSI/ESDA/JEDEC JS-001 Table 3	JEDEC JESD22 A114-D
Charge Device Model	CDM	C3	ANSI/ESDA/JEDEC JS-002 Table 3	JEDEC JESD22 C101-C

Simulated Source and Load Impedances



Frequency (MHz)	Z Source	Z Load
500	4.1 + j5.27	14.73 + j6.91
750	2.9 + j4.1	12.3 + j7.6
1000	2.48 + j0.06	8.13 + j6.85
1100	1.9 + j3.1	9.2 + j6.2
1500	2.1 - j2.5	6.0 + j4.3
1700	1.05 - j2.48	5.07 + j2.29
1800	2.1 - j1.9	5.8 + j4.1
1900	0.89 - j2.62	4.81 + j2.17
2000	0.69 - j3.75	4.93 + j0.16
2100	1.5 - j4.4	5.1 + j2.8
3000	1.06 - j8.92	4.04 - j2.98
4000	1.67 - j18.1	4.97 - j8.25

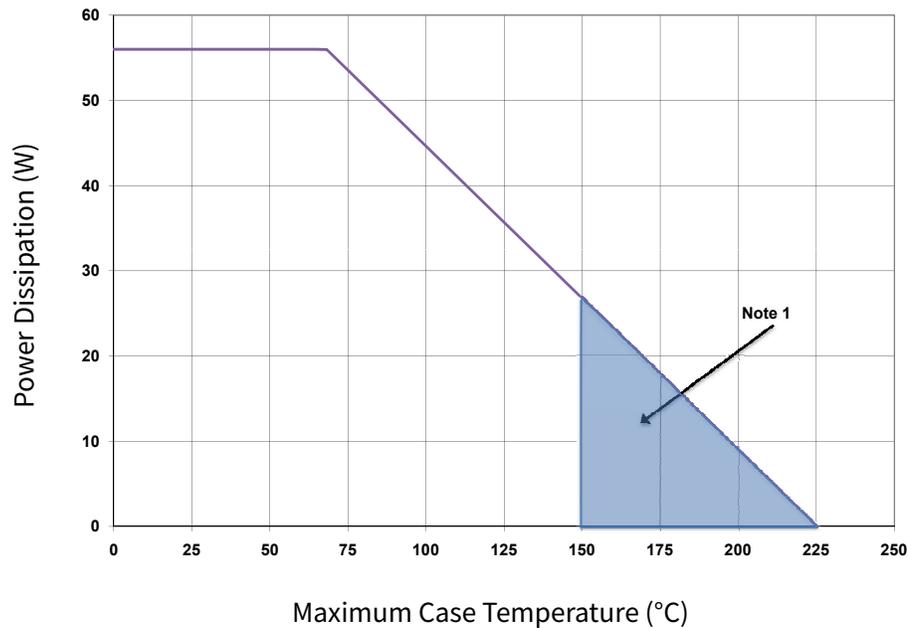
Notes:

¹ $V_{DD} = 28V$, $I_{DQ} = 800$ mA in the 440193 package.

² Optimized for power gain, P_{SAT} and PAE.

³ When using this device at low frequency, series resistors should be used to maintain amplifier stability

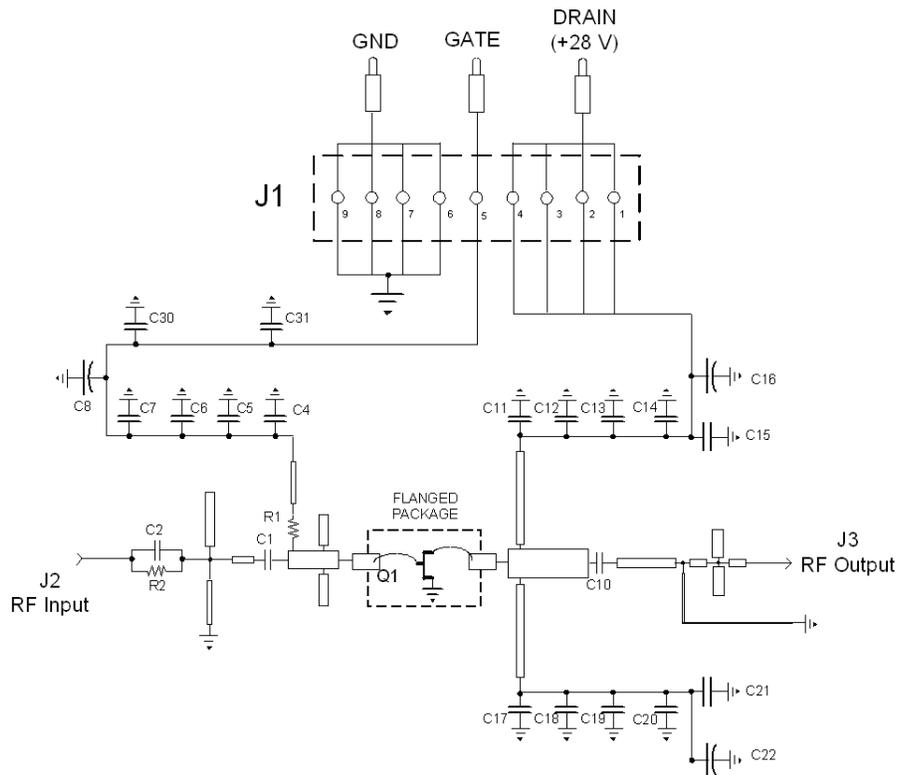
CGH40045 Power Dissipation De-rating Curve



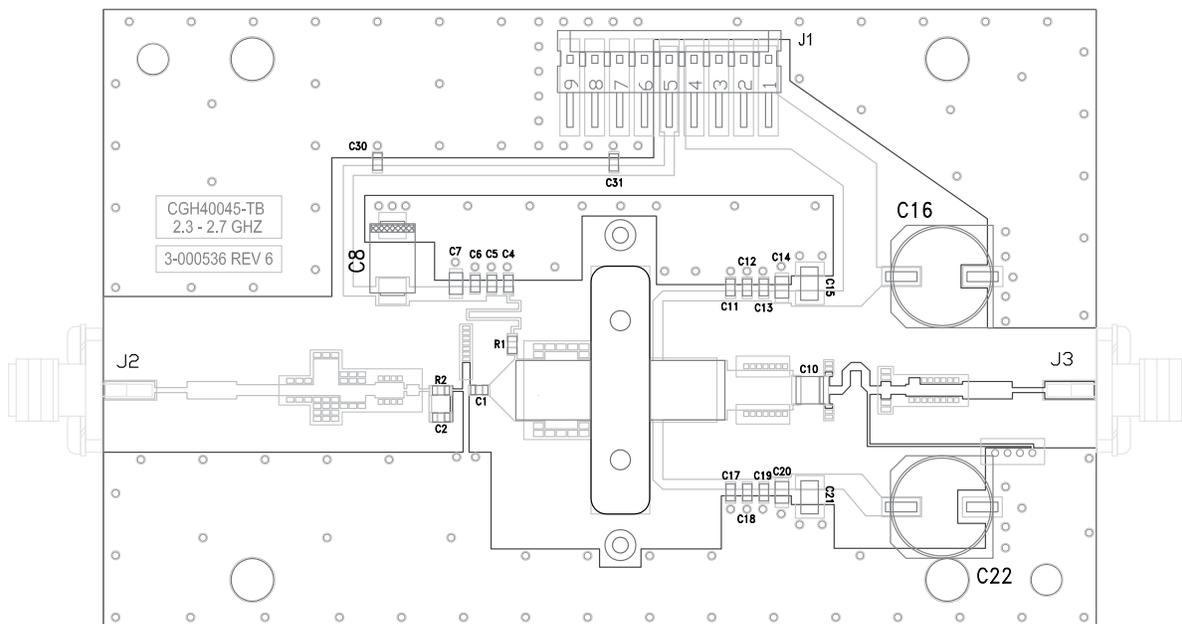
Note:

¹ Area exceeds Maximum Case Operating Temperature (See Page 2).

CGH40045-AMP Demonstration Amplifier Circuit Schematic



CGH40045-AMP Demonstration Amplifier Circuit Outline

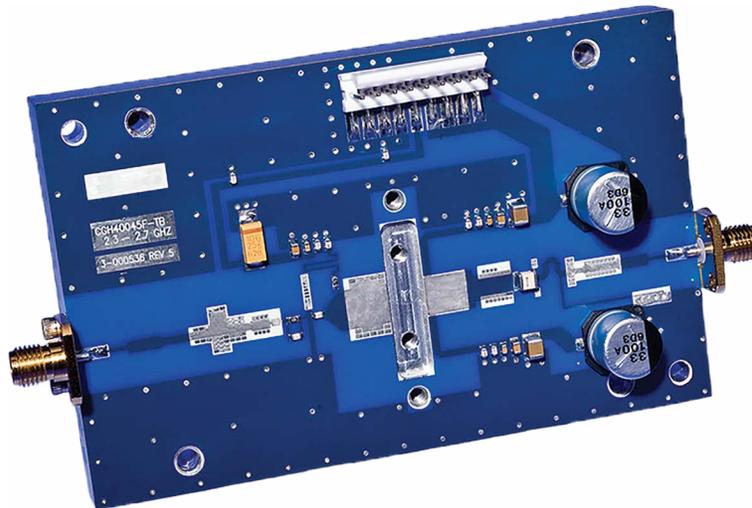


Note: The device slot is machined to different depths to support either pill or flanged versions

CGH40045-AMP Demonstration Amplifier Circuit Bill of Materials

Designator	Description	Qty
C1	CAP, 0.8pF, ± 0.1 pF, 0603	1
C2	CAP, 2.2pF, ± 0.1 pF, 0603	1
C4, C11, C17	CAP, 10.0pF, +/-5%, 0603, ATC	3
C6, C13, C19	CAP, 470pF $\pm 5\%$, 100V, 0603, X7R	3
C7, C14, C20	CAP, 33000pF, 0805, 100V, X7R	3
C8	CAP, 10 μ F, 16V, SMT, TANTALUM	1
C10	CAP, 8.2pF $\pm 5\%$, ATC100B	1
C15, C21	CAP, 1.0 μ F $\pm 10\%$, 100V, 1210, X7R	2
C5, C12, C18, C30, C31	CAP, 82.0pF, $\pm 5\%$, 0603	5
C16, C22	CAP, 33 μ F, 20%, G CASE	2
R2	RES, 1/16W, 0603, 100 ohms 1%	1
R1	RES, 1/16W, 0603, 5.1 ohms 1%	1
J2, J3	CONN, SMA, PANEL MOUNT JACK, FLANGE	2
J1	CONN, HEADER, RT>PLZ .1CEN LK 9POS	1
-	PCB, RO4350B, Er = 3.48, h = 20 mil	1
Q1	CGH40045	1

CGH40045-AMP Demonstration Amplifier Circuit



Typical Package S-Parameters for CGH40045
(Small Signal, $V_{DS} = 28\text{ V}$, $I_{DQ} = 400\text{ mA}$, angle in degrees)

Frequency	Mag S11	Ang S11	Mag S21	Ang S21	Mag S12	Ang S12	Mag S22	Ang S22
500 MHz	0.941	-171.75	7.34	80.91	0.012	-3.58	0.650	-173.39
600 MHz	0.941	-174.07	6.12	77.22	0.012	-6.14	0.655	-173.73
700 MHz	0.941	-175.88	5.24	73.81	0.012	-8.41	0.660	-173.93
800 MHz	0.942	-177.39	4.59	70.58	0.012	-10.49	0.665	-174.05
900 MHz	0.942	-178.70	4.07	67.49	0.012	-12.42	0.671	-174.15
1.0 GHz	0.942	-179.88	3.66	64.51	0.011	-14.23	0.677	-174.24
1.1 GHz	0.943	-179.05	3.33	61.61	0.011	-15.93	0.683	-174.35
1.2 GHz	0.943	-178.03	3.05	58.78	0.011	-17.54	0.689	-174.49
1.3 GHz	0.944	-177.07	2.82	56.03	0.011	-19.06	0.695	-174.66
1.4 GHz	0.944	-176.13	2.62	53.33	0.011	-20.50	0.701	-174.86
1.5 GHz	0.945	-175.21	2.45	50.69	0.011	-21.86	0.707	-175.10
1.6 GHz	0.945	-174.30	2.30	48.10	0.011	-23.14	0.713	-175.37
1.7 GHz	0.945	-173.40	2.17	45.56	0.011	-24.34	0.718	-175.68
1.8 GHz	0.946	-172.49	2.06	43.05	0.010	-25.47	0.724	-176.02
1.9 GHz	0.946	-171.58	1.96	40.59	0.010	-26.53	0.729	-176.40
2.0 GHz	0.946	-170.65	1.87	38.16	0.010	-27.51	0.734	-176.81
2.1 GHz	0.946	-169.70	1.80	35.76	0.010	-28.43	0.739	-177.25
2.2 GHz	0.946	-168.73	1.73	33.39	0.010	-29.28	0.743	-177.72
2.3 GHz	0.946	-167.73	1.67	31.03	0.010	-30.06	0.747	-178.21
2.4 GHz	0.945	-166.70	1.62	28.70	0.010	-30.78	0.751	-178.74
2.5 GHz	0.945	-165.63	1.57	26.37	0.010	-31.44	0.754	-179.28
2.6 GHz	0.945	-164.53	1.54	24.06	0.010	-32.05	0.757	-179.85
2.7 GHz	0.944	-163.38	1.50	21.74	0.009	-32.60	0.759	-179.55
2.8 GHz	0.943	-162.17	1.47	19.42	0.009	-33.10	0.761	-178.93
2.9 GHz	0.942	-160.91	1.45	17.09	0.009	-33.56	0.763	-178.28
3.0 GHz	0.941	-159.57	1.43	14.74	0.009	-33.99	0.764	-177.61
3.2 GHz	0.938	-156.68	1.41	9.95	0.009	-34.75	0.766	-176.20
3.4 GHz	0.935	-153.41	1.41	5.00	0.009	-35.46	0.765	-174.68
3.6 GHz	0.930	-149.66	1.42	-0.20	0.010	-36.21	0.763	-173.05
3.8 GHz	0.923	-145.28	1.46	-5.76	0.010	-37.13	0.758	-171.27
4.0 GHz	0.914	-140.09	1.52	-11.80	0.011	-38.39	0.751	-169.35
4.2 GHz	0.903	-133.82	1.60	-18.50	0.011	-40.21	0.742	-167.23
4.4 GHz	0.888	-126.08	1.71	-26.07	0.012	-42.86	0.729	-164.90
4.6 GHz	0.868	-116.32	1.86	-34.83	0.013	-46.72	0.712	-162.27
4.8 GHz	0.842	-103.74	2.05	-45.14	0.015	-52.24	0.690	-159.29
5.0 GHz	0.811	-87.25	2.27	-57.50	0.017	-59.93	0.663	-155.80
5.2 GHz	0.777	-65.61	2.51	-72.38	0.019	-70.34	0.628	-151.60
5.4 GHz	0.752	-38.13	2.72	-90.03	0.021	-83.73	0.581	-146.39
5.6 GHz	0.753	6.31	2.83	-110.07	0.023	-99.76	0.516	-139.81
5.8 GHz	0.785	-25.54	2.78	-131.39	0.023	-117.31	0.427	-131.59
6.0 GHz	0.835	-53.19	2.58	-152.64	0.022	-135.03	0.311	-121.26

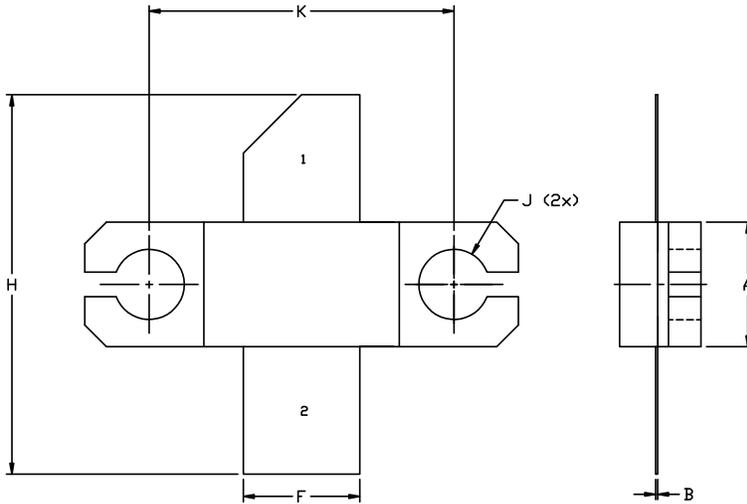
To download the s-parameters in s2p format, go to the CGH40045 Product page.

Typical Package S-Parameters for CGH40045
(Small Signal, $V_{DS} = 28\text{ V}$, $I_{DQ} = 800\text{ mA}$, angle in degrees)

Frequency	Mag S11	Ang S11	Mag S21	Ang S21	Mag S12	Ang S12	Mag S22	Ang S22
500 MHz	0.952	-172.90	7.23	81.83	0.009	-1.13	0.688	-176.19
600 MHz	0.952	-175.11	6.03	78.47	0.009	-3.05	0.691	-176.58
700 MHz	0.952	-176.85	5.18	75.35	0.009	-4.72	0.694	-176.86
800 MHz	0.952	-178.32	4.54	72.38	0.009	-6.21	0.696	-177.07
900 MHz	0.952	-179.59	4.05	69.53	0.009	-7.58	0.699	-177.25
1.0 GHz	0.952	179.25	3.65	66.76	0.009	-8.84	0.702	-177.42
1.1 GHz	0.952	178.19	3.33	64.06	0.009	-10.01	0.706	-177.59
1.2 GHz	0.952	177.18	3.06	61.42	0.009	-11.09	0.709	-177.77
1.3 GHz	0.952	176.22	2.83	58.82	0.009	-12.11	0.712	-177.96
1.4 GHz	0.952	175.28	2.64	56.27	0.009	-13.05	0.716	-178.17
1.5 GHz	0.952	174.37	2.48	53.75	0.009	-13.92	0.719	-178.41
1.6 GHz	0.952	173.46	2.34	51.27	0.009	-14.72	0.722	-178.67
1.7 GHz	0.952	172.55	2.21	48.82	0.009	-15.46	0.725	-178.95
1.8 GHz	0.952	171.64	2.11	46.39	0.009	-16.14	0.728	-179.26
1.9 GHz	0.952	170.72	2.01	43.99	0.009	-16.75	0.731	-179.59
2.0 GHz	0.951	169.78	1.93	41.60	0.009	-17.29	0.734	-179.94
2.1 GHz	0.951	168.83	1.86	39.23	0.009	-17.78	0.737	179.67
2.2 GHz	0.951	167.85	1.80	36.88	0.008	-18.21	0.739	179.27
2.3 GHz	0.950	166.84	1.74	34.53	0.008	-18.58	0.741	178.83
2.4 GHz	0.949	165.80	1.69	32.19	0.008	-18.90	0.743	178.38
2.5 GHz	0.949	164.73	1.65	29.85	0.008	-19.17	0.744	177.90
2.6 GHz	0.948	163.61	1.61	27.51	0.008	-19.40	0.746	177.39
2.7 GHz	0.947	162.44	1.58	25.15	0.008	-19.59	0.747	176.86
2.8 GHz	0.946	161.22	1.56	22.79	0.008	-19.74	0.747	176.31
2.9 GHz	0.945	159.94	1.54	20.40	0.009	-19.87	0.748	175.73
3.0 GHz	0.943	158.58	1.53	17.98	0.009	-19.99	0.747	175.12
3.2 GHz	0.940	155.64	1.51	13.04	0.009	-20.21	0.746	173.83
3.4 GHz	0.935	152.30	1.51	7.90	0.009	-20.51	0.743	172.44
3.6 GHz	0.930	148.47	1.54	2.47	0.010	-21.01	0.738	170.92
3.8 GHz	0.922	143.99	1.58	-3.34	0.010	-21.86	0.730	169.27
4.0 GHz	0.913	138.66	1.65	-9.68	0.011	-23.25	0.721	167.47
4.2 GHz	0.900	132.21	1.75	-16.72	0.012	-25.41	0.708	165.49
4.4 GHz	0.884	124.23	1.87	-24.68	0.013	-28.63	0.691	163.32
4.6 GHz	0.863	114.16	2.04	-33.86	0.015	-33.25	0.671	160.90
4.8 GHz	0.835	101.18	2.24	-44.66	0.017	-39.70	0.646	158.17
5.0 GHz	0.802	84.20	2.47	-57.54	0.020	-48.45	0.616	155.00
5.2 GHz	0.768	62.03	2.72	-72.91	0.022	-59.96	0.577	151.18
5.4 GHz	0.745	34.19	2.91	-90.96	0.025	-74.38	0.527	146.39
5.6 GHz	0.750	2.50	2.99	-111.20	0.026	-91.25	0.459	140.32
5.8 GHz	0.785	-28.66	2.91	-132.50	0.027	-109.41	0.366	132.93
6.0 GHz	0.837	-55.46	2.67	-153.57	0.025	-127.56	0.245	124.60

To download the s-parameters in s2p format, go to the CGH40045 Product page.

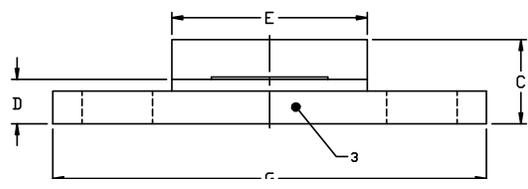
Product Dimensions CGH40045F (Package Type — 440193)



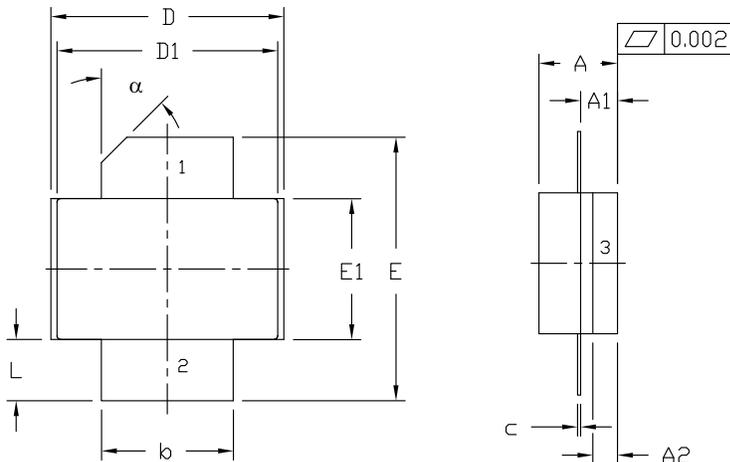
- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF 0.020" BEYOND EDGE OF LID.
 4. LID MAY BE MISALIGNED TO THE BODY OF THE PACKAGE BY A MAXIMUM OF 0.008" IN ANY DIRECTION.
 5. ALL PLATED SURFACES ARE NI/AU

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.225	0.235	5.72	5.97
B	0.004	0.006	0.10	0.15
C	0.145	0.165	3.18	4.19
D	0.077	0.087	1.96	2.21
E	0.355	0.365	9.02	9.27
F	0.210	0.220	5.33	5.59
G	0.795	0.805	20.19	20.45
H	0.670	0.730	17.02	18.54
J	ø .130		3.30	
k	0.562		14.28	

- PIN 1. GATE
 PIN 2. DRAIN
 PIN 3. SOURCE



Product Dimensions CGH40045P (Package Type — 440206)

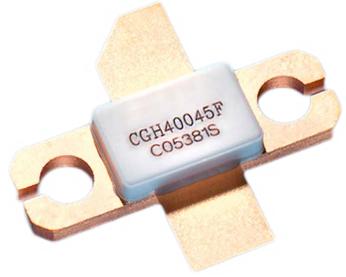
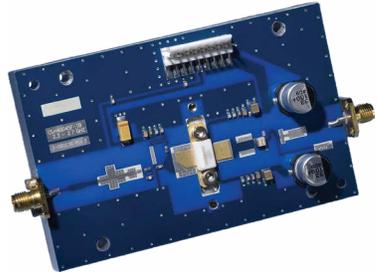


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M - 1994.
 2. CONTROLLING DIMENSION: INCH.
 3. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF 0.020" BEYOND EDGE OF LID.
 4. LID MAY BE MISALIGNED TO THE BODY OF PACKAGE BY A MAXIMUM OF 0.008" IN ANY DIRECTION.

DIM	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	0.125	0.145	3.18	3.68	
A1	0.057	0.067	1.45	1.70	
A2	0.035	0.045	0.89	1.14	
b	0.210	0.220	5.33	5.59	2x
c	0.004	0.006	0.10	0.15	2x
D	0.375	0.385	9.53	9.78	
D1	0.355	0.365	9.02	9.27	
E	0.400	0.460	10.16	11.68	
E1	0.225	0.235	5.72	5.97	
L	0.085	0.115	2.16	2.92	2x
alpha	45° REF		45° REF		

- PIN 1. GATE
 PIN 2. DRAIN
 PIN 3. SOURCE

Product Ordering Information

Order Number	Description	Unit of Measure	Image
CGH40045F	GaN HEMT	Each	
CGH40045P	GaN HEMT	Each	
CGH40045F-AMP	Test board with GaN HEMT installed	Each	
CGH40045P-AMP	Test board with GaN HEMT installed	Each	

Notes & Disclaimer

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